

172A 3003

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

MASAYUKI ISHIKAWA et al.

Serial No.: 09/679,984

Filed: October 5, 2000

PIEZOELECTRIC OSCILLATOR For:

2817 Art Unit:

Arnold M. Kinkead Examiner:

AMENDMENT

TECHNOLOGY CERTER 2800

01 FU: 1 ...

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Commissioner for Patents Washington, D.C. 20231

Dear Sir:

In response to the Office Action dated February 19, 2002, please amend the aboveidentified application as follows:

IN THE SPECIFICATION:

Please replace page 1, first full paragraph, with the following rewritten paragraph:

-- The present invention relates to a piezoelectric oscillator and, more particularly, to a piezoelectric oscillator that uses a MOS construction type capacitance element.--

Please replace page 3, third full paragraph, with the following rewritten paragraph:

--On the other hand, as a variable-capacitance element suited to conversion to IC version, there is known a MOS construction type capacitance element, the utilization of that has been in expectation.--

Please replace page 3, fourth full paragraph, with the following rewritten paragraph:

--As a crystal oscillator using such a MOS construction type capacitance element, there is the one that is disclosed, for example, in Japanese Patent Application Laid-Open No. 10-13155 entitled "Crystal Resonator with Frequency-Adjusting Function" .--

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